
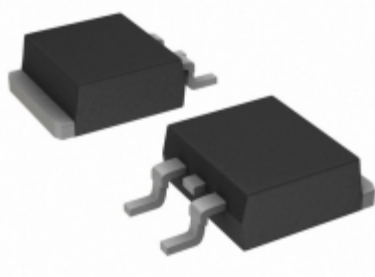
	<h2 style="color: red;">FQB22P10TM</h2> <p><b>Hersteller-Teilenummer:</b> FQB22P10TM</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 100V 22A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB22P10TM.pdf</a></p> <p><b>RoHS Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 42109 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB22P10TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 100V 22A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	42109 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 125W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	22A (Tc)
Rds On (Max) @ Id, Vgs	125 mOhm @ 11A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)












































FQB22P10TM ist neu im Original, Suche FQB22P10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB22P10TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB22P10TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB20N60LTM</b> FS FS TO-263	 <b>FQB22P10</b> FAIRCHILD FQB22P10 FAIRCHILD	 <b>FQB24N08TM</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 24A D2PAK	 <b>FQB24N08</b> FSC FSC TO-263
 <b>FQB20N06TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A D2PAK	 <b>FQB20N60FTM</b> FAIRCHILD FQB20N60FTM FAIRCHILD	 <b>FQB22P10TM_F085</b> Fairchild/ON Semiconductor FQB22P10TM_F085 Fairchild/ON Semiconductor	 <b>FQB20N60TM</b> FAIRCHILD FQB20N60TM FAIRCHILD

### heiße Teile

Mehr

 FQB17P06	 FQB17P10	 FQB17P10TM	 FQB17P10TM	 FQB19N10L
 FQB19N10LTM	 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20
 FQB19N20C	 FQB19N20CTM	 FQB19N20CTM	 FQB19N20L	 FQB19N20LTM
 FQB19N20LTM	 FQB19N20TM	 FQB19N20TM	 FQB1N60TM	 FQB1N60TM
 FQB20N06L	 FQB20N60FTM	 FQB20N60TM	 FQB22P10	 FQB22P10TM
 FQB22P10TM_F085	 FQB24N08TM	 FQB24N08TM	 FQB25N33	 FQB25N33TM
 FQB25N33TM	 FQB25N33TM_F085	 FQB27N25TM	 FQB27P06	 FQB27P06TM
 FQB27P06TM	 FQB2N50C	 FQB2N60TM	 FQB2N60TM	 FQB2N80TM
 FQB2N80TM	 FQB2NA90TM	 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM
 FQB30N06	 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM	 FQB30N06TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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